Max. Marks: 70

**Code No: R20A0402** 

Time: 3 hours

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## MALLA REDDY COLLEGE OF ENGINEERING & TECHNOLOGY

(Autonomous Institution – UGC, Govt. of India)

## II B.Tech I Semester Supplementary Examinations, July/August 2023 Electronic Devices & Circuits

(ECE)											
Roll No											

**Note:** This question paper Consists of 5 Sections. Answer **FIVE** Questions, Choosing ONE

Question from each SECTION and each Question carries 14 marks. **SECTION-I** Explain the operation of Bridge rectifier. 1  $\boldsymbol{A}$ [7M] Compare the performance of Half wave rectifier, Full wave rectifier and B [7M] Bridge Rectifier. OR 2 Describe the function of FWR with Capacitor filter with the help of circuit [7M] diagram. Compute ripple factor of an C – section choke input filter used at the output of a B [7M] Full wave rectifier and capacitor values of the filter are given as 10 H and 8.2 µF respectively. **SECTION-II** 3 Explain the collector to base bias circuit and find the stability factor. [7M]  $\boldsymbol{A}$ (i) A germanium transistor is to be operated at zero signal  $I_C = 1$ mA. If the  $\boldsymbol{B}$ [7M] collector supply  $V_{CC} = 12V$ , what is the value of  $R_B$  in the base resistor method ? Take  $\beta = 100$ . (ii) If another transistor of the same batch with  $\beta = 50$  is used, what will be the new value of zero signal I<sub>C</sub> for the same R<sub>B</sub>? OR Why Self bias circuit is more preferable comparing to Fixed bias circuit? 4 [9M] Draw the Voltage divider bias and derive expressions for Thevenin's voltage, Thevenin's resistance and stability factor. В What is Thermal runaway? How it impacts on stability? [5M] **SECTION-III** 5 The h parameters of the transistor circuit as follows  $h_{ie}=4K\Omega$ ,  $h_{re}=7\times 10^{-4}$ , [7M]  $\boldsymbol{A}$ h<sub>fe</sub>=100, h<sub>oe</sub>=50µmhos. Find h parameters for CB configuration. Find current gain if the load resistance is  $1000 \Omega$ .  $\boldsymbol{B}$ Draw BJT Hybrid model and define h parameters. [7M] 6 Draw the basic transistor amplifier circuit and its equivalent h parameter  $\boldsymbol{A}$ [7M]

model. Find its input impedance and output impedance.

What are the advantages of negative feedback? Explain.

expression for feedback factor in each case.

Compare various transistor configurations in terms of A<sub>i</sub>, R<sub>i</sub>, A<sub>v</sub> and R<sub>o</sub>

**SECTION-IV** 

Describe various feedback topologies with help of block diagrams. Write

[7M]

[6M]

[8M]

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8	$\boldsymbol{A}$	Explain briefly about classifications of an Oscillators.	[6M]
	В	Illustrate the operation of RC Phase Shift Oscillator and also derive the expression for frequency of oscillation.	[8M]
9	$\boldsymbol{A}$	SECTION-V What are the various FET biasing circuits? Explain briefly.	[7M]
	$\boldsymbol{B}$	Explain the working principle of Photo diode.	[7M]
		OR	
10	$\boldsymbol{A}$	Describe the principle and operation of Varactor diode.	[8M]
	$\boldsymbol{B}$	List the applications of Varactor diode.	[6M]

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